

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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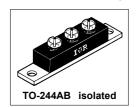


International Rectifier

201CMQ... SERIES

SCHOTTKY RECTIFIER

200 Amp



Major Ratings and Characteristics

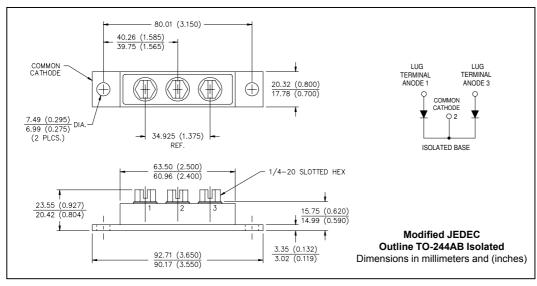
Cha	racteristics	201CMQ	Units
I _{F(AV)}	Rectangular waveform	200	А
V _{RRM}	l	35 to 45	V
I _{FSM}	@ tp = 5 µs sine	16,000	Α
V _F	@100Apk, T _J =125°C (per leg)	0.58	V
T _J	range	-55 to 175	°C

Description/Features

The 201CMQ high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature.

The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, free-wheeling diodes, welding, and reverse battery protection.

- 175 °C T_J operation
- Center tap module Isolated Base
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Bulletin PD-2.400 rev. B 08/01

International TOR Rectifier

Voltage Ratings

Part number	201CMQ035	201CMQ040	201CMQ045
V _R Max. DC Reverse Voltage (V)	35	40	45
V _{RWM} Max. Working Peak Reverse Voltage (V)			

Absolute Maximum Ratings

	Parameters		201CMQ	Units	Conditions	
I _{F(AV)}	F(AV) Max. Average Forward (Per Leg)		100	Α	50% duty cycle @ T _C = 121 °C,	rectangular wave form
	Current *See Fig. 5 (F	Per Device)	200			
I _{FSM}	Max. Peak One Cycle Non-F	Repetitive	16,000	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with
	Surge Current (Per Leg) *S	See Fig. 7	3200		10ms Sine or 6ms Rect. pulse	rated V _{RRM} applied
E _{AS}	Non-RepetitiveAvalancheEnergy		135	mJ	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 20 \text{Amps}, L =$	0.67 mH
	(Per Leg)					
I _{AR}	AR Repetitive Avalanche Current		20	Α	Current decaying linearly to zero in 1 µsec	
	(Per Leg)				Frequency limited by T _J max. \	_A =1.5xV _R typical

Electrical Specifications

	-				
	Parameters	201CMQ	Units	C	Conditions
V_{FM}	Max. Forward Voltage Drop	0.67	V	@ 100A	T ₁ = 25 °C
1	(Per Leg) * See Fig. 1 (1)	0.81	V	@ 200A	1 _J = 23 0
		0.58	V	@ 100A	T 405 °C
		0.71	٧	@ 200A	T _J = 125 °C
I _{RM}	Max. Reverse Leakage Current	10	mA	T _J = 25 °C	V _p = rated V _p
	(Per Leg) * See Fig. 2 (1)	90	mA	T _J = 125 °C	v _R = rated v _R
C _T	Max. Junction Capacitance (Per Leg)	5200	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C	
L _s	Typical Series Inductance (Per Leg)	7.0	nΗ	From top of terminal hole to mounting plane	
dv/dt	Max. Voltage Rate of Change	10000	V/ µs	(Rated V _R)	
V_{RMS}	Insulation Voltage	1000	V		

Thermal-Mechanical Specifications

(1) Pulse Width < 300 μ s, Duty Cycle <2%

	Parameters		201CMQ	Units	Conditions
T _J	Max. Junction Temperature Range		-55 to 175	°C	
T _{stg}	Max. Storage Temperature Range		-55 to 175	°C	
R _{thJC}			0.70	°C/W	DC operation *See Fig. 4
	to Case (Per Leg)				
R _{thJC}	Max. Thermal Resistance Junction		0.35	°C/W	DCoperation
	to Case (Per Package)				
R _{thCS}	S Typical Thermal Resistance, Case		0.10	°C/W	Mounting surface, smooth and greased
	to Heatsink				
wt	Approximate Weight		79 (2.80)	g(oz.)	
Т	Mounting Torque	Min.	24 (20)		
		Max.	35(30)	Kg-cm	
	Mounting Torque Center Hole	Тур.	13.5(12)	(lbf-in)	
	Terminal Torque	Min.	35(30)	()	
		Max.	46 (40)		
	Case Style		TO-244AB	solated	Modified JEDEC

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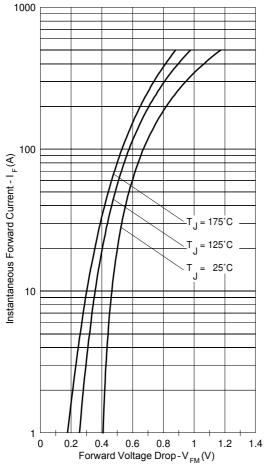


Fig. 1-Max. Forward Voltage Drop Characteristics

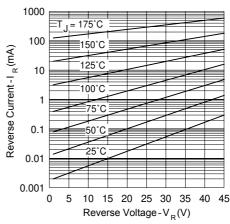


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

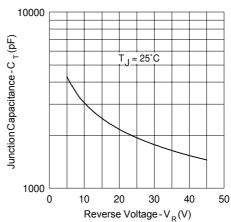


Fig. 3-Typical Junction Capacitance
Vs. Reverse Voltage

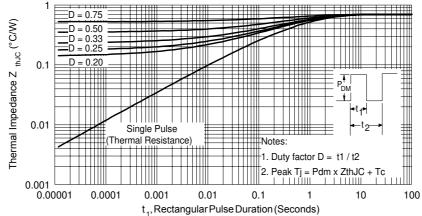
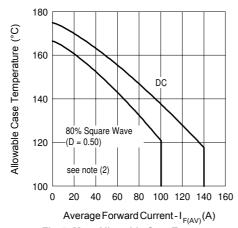


Fig.4-Max. Thermal Impedance Z_{thJC} Characteristics (PerLeg)

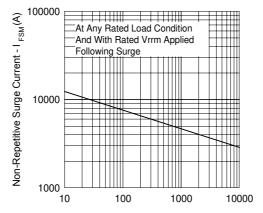
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90 D = 0.75 D = 0.50 -D = 0.33Average Power Loss (Watts) D = 0.25D = 0.2060 30 0 0 30 60 90 120 150 $Average \, Forward \, Current \, \text{--} \, I_{F(AV)}(A)$

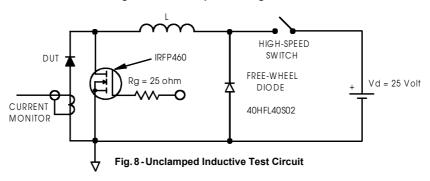
Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

Fig. 6-Forward Power Loss Characteristics



Square Wave Pulse Duration - t $_{\rm p}$ (microsec)

Fig. 7 - Max. Non-Repetitive Surge Current

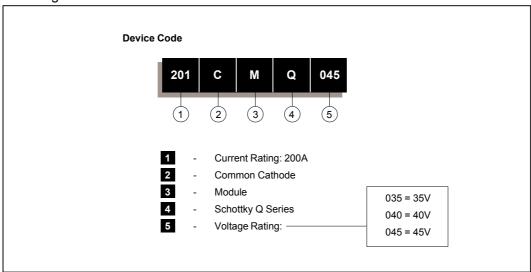


(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward Power Loss = I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6); $Pd_{REV} = Inverse Power Loss = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\%$ rated V_R

201CMQ... Series

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Ordering Information Table



Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level.

Qualification Standards can be found on IR's Web site.



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